

# **PSMN3R3-100SSF**

NextPower 100 V, 3.3 m $\Omega$ , 190 Amp, N-channel MOSFET in LFPAK88 package

9 June 2020

**Objective data sheet** 

## 1. General description

NextPower 100 V, standard level gate drive MOSFET. Qualified to 175 °C and recommended for industrial and consumer applications.

#### 2. Features and benefits

- Low Q<sub>rr</sub> for higher efficiency and lower spiking
- 190 Amps I<sub>D(max)</sub> continuous current rating
- Low Q<sub>G</sub> × R<sub>DSon</sub> FOM for high efficiency switching applications
- Strong avalanche energy rating (E<sub>as</sub>)
- Avalanche rated and 100% tested
- Ha-free and RoHS compliant LFPAK88 package

### 3. Applications

- Synchronous rectifier in AC-DC and DC-DC
- · Primary side switch in DC-DC
- · BLDC motor control
- · Full-bridge and half-bridge applications
- Battery protection

### 4. Quick reference data

#### Table 1. Quick reference data

| Symbol               | Parameter   | Conditions  |     | Min   | Тур  | Max   | Unit |
|----------------------|---|---|-----|-------|------|-------|------|
| $V_{DS}$             | drain-source voltage                                | 25 °C ≤ T <sub>j</sub> ≤ 175 °C   |     | -     | -    | 100   | V    |
| I <sub>D</sub>       | drain current                                       | V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C   |     | -     | -    | 190   | Α    |
| P <sub>tot</sub>     | total power dissipation                             | T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>  |     | -     | -    | 341   | W    |
| Tj                   | junction temperature                                |   |     | -55   | -    | 175   | °C   |
| Static characte      | eristics  |   |     |       |      |       |      |
| R <sub>DSon</sub>    | drain-source on-state resistance                    | V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 25 °C   |     | -     | 2.56 | 3.3   | mΩ   |
|                      |   | V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 100 °C  |     | -     | 4.1  | 5.3   | mΩ   |
| Dynamic chara        | acteristics   |   |     |       |      |       |      |
| $Q_{GD}$             | gate-drain charge                                   | I <sub>D</sub> = 25 A; V <sub>DS</sub> = 50 V; V <sub>GS</sub> = 10 V   |     | [tbd] | 20   | [tbd] | nC   |
| Q <sub>G(tot)</sub>  | total gate charge                                   |   |     | [tbd] | 101  | [tbd] | nC   |
| Avalanche rug        | gedness   |   |     |       |      |       | '    |
| E <sub>DS(AL)S</sub> | non-repetitive drain-<br>source avalanche<br>energy | $I_D$ = 62 A; $V_{sup} \le 100$ V; $R_{GS}$ = 50 Ω; $V_{GS}$ = 10 V; $T_{j(init)}$ = 25 °C; unclamped; Fig. 2 | [1] | -     | -    | 478   | mJ   |



| Symbol         | Parameter          | Conditions  |  | Min | Тур | Max | Unit |
|----------------|--------------------|---|--|-----|-----|-----|------|
| Source-drain d | Source-drain diode |   |  |     |     |     |      |
| Q <sub>r</sub> | recovered charge   | $I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; Fig. 3$ |  | -   | 57  | -   | nC   |

<sup>[1]</sup> Protected by 100% test

## 5. Pinning information

**Table 2. Pinning information** 

| Pin | Symbol | Description                       | Simplified outline | Graphic symbol |
|-----|--------|-----------------------------------|--------------------|----------------|
| 1   | G      | gate                              |                    | D              |
| 2   | S      | source                            |                    |                |
| 3   | S      | source                            |                    | G—(F           |
| 4   | S      | source                            |                    | mbb076 S       |
| mb  | D      | mounting base; connected to drain | LFPAK88 (SOT1235)  |                |

### 6. Ordering information

**Table 3. Ordering information** 

| Type number    | Package |   |         |  |  |  |
|----------------|---------|---|---------|--|--|--|
|                | Name    | Description   | Version |  |  |  |
| PSMN3R3-100SSF | LFPAK88 | plastic, single-ended surface-mounted package (LFPAK88); 4 leads; 2 mm pitch; 8 mm x 8 mm x 1.6 mm body | SOT1235 |  |  |  |

## 7. Limiting values

#### **Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol              | Parameter                     | Conditions  | Min | Max | Unit |
|---------------------|-------------------------------|---|-----|-----|------|
| $V_{DS}$            | drain-source voltage          | 25 °C ≤ T <sub>j</sub> ≤ 175 °C   | -   | 100 | V    |
| $V_{DGR}$           | drain-gate voltage            | $25  ^{\circ}$ C ≤ T <sub>j</sub> ≤ 175 $^{\circ}$ C; R <sub>GS</sub> = 20 kΩ | -   | 100 | V    |
| $V_{GS}$            | gate-source voltage           |   | -20 | 20  | V    |
| P <sub>tot</sub>    | total power dissipation       | T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>  | -   | 341 | W    |
| I <sub>D</sub>      | drain current                 | V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C                               | -   | 190 | А    |
|                     |                               | V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 100 °C                              | -   | 151 | Α    |
| I <sub>DM</sub>     | peak drain current            | pulsed; $t_p \le 10 \mu s$ ; $T_{mb} = 25 °C$                                 | -   | 760 | А    |
| T <sub>stg</sub>    | storage temperature           |   | -55 | 175 | °C   |
| T <sub>j</sub>      | junction temperature          |   | -55 | 175 | °C   |
| T <sub>sld(M)</sub> | peak soldering<br>temperature |   | -   | 260 | °C   |
| Source-drain        | n diode                       |   |     |     |      |
| Is                  | source current                | T <sub>mb</sub> = 25 °C   | -   | 190 | А    |
| I <sub>SM</sub>     | peak source current           | pulsed; $t_p \le 10 \mu s$ ; $T_{mb} = 25 \text{ °C}$                         | -   | 760 | А    |

| Symbol               | Parameter  | Conditions   |     | Min | Max | Unit |  |
|----------------------|--|--|-----|-----|-----|------|--|
| Avalanche ruggedness |  |  |     |     |     |      |  |
|                      | non-repetitive drain-<br>source avalanche energy | $I_D$ = 62 A; $V_{sup} \le 100$ V; $R_{GS}$ = 50 Ω; $V_{GS}$ = 10 V; $T_{j(init)}$ = 25 °C; unclamped; Fig. 2    | [1] | -   | 478 | mJ   |  |
| I <sub>AS</sub>      | non-repetitive avalanche current                 | $V_{sup} \le 100 \text{ V}; V_{GS} = 10 \text{ V}; T_{j(init)} = 25 \text{ °C};$<br>$R_{GS} = 50 \Omega; Fig. 2$ | [1] | -   | 62  | А    |  |

#### [1] Protected by 100% test

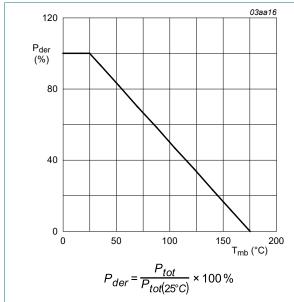


Fig. 1. Normalized total power dissipation as a function of mounting base temperature

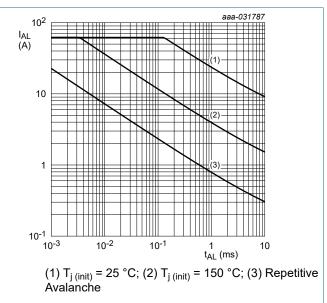


Fig. 2. Avalanche rating; avalanche current as a function of avalanche time

### 8. Thermal characteristics

#### **Table 5. Thermal characteristics**

| Symbol                | Parameter   | Conditions | Min | Тур   | Max  | Unit |
|-----------------------|---|------------|-----|-------|------|------|
| R <sub>th(j-mb)</sub> | thermal resistance from junction to mounting base |            | -   | [tbd] | 0.44 | K/W  |

### 9. Characteristics

**Table 6. Characteristics** 

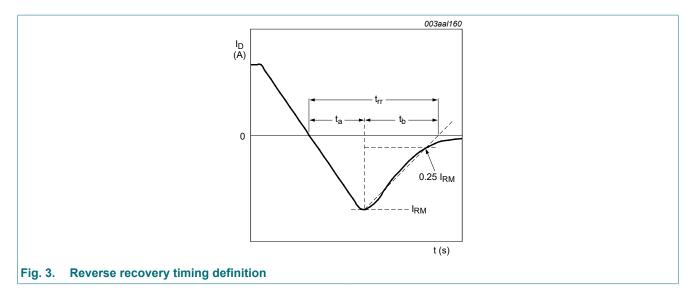
| Symbol                       | Parameter  | Conditions  | Min | Тур  | Max      | Unit |
|------------------------------|--|---|-----|------|----------|------|
| Static chara                 | cteristics   |   |     |      | <u> </u> |      |
| - (DIC)D33                   | drain-source   | I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C  | 100 | -    | -        | V    |
|                              | breakdown voltage  | I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = -55 °C | 90  | -    | -        | V    |
| V <sub>GS(th)</sub>          | gate-source threshold                                    | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$              | 2   | 3    | 4        | V    |
|                              | voltage  | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C}$             | -   | 3.5  | -        | V    |
|                              |  | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ °C}$             | -   | 1.6  | -        | V    |
| $\Delta V_{GS(th)}/\Delta T$ | gate-source threshold voltage variation with temperature | 25 °C ≤ T <sub>j</sub> ≤ 150 °C   | -   | -8.4 | -        | mV/K |

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| Symbol                 | Parameter                             | Conditions  | Min   | Тур  | Max   | Unit |
|------------------------|---------------------------------------|---|-------|------|-------|------|
| I <sub>DSS</sub>       | drain leakage current                 | V <sub>DS</sub> = 100 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C  | -     | 0.1  | 25    | μΑ   |
|                        |                                       | V <sub>DS</sub> = 100 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 125 °C   | -     | -    | 100   | μΑ   |
| I <sub>GSS</sub>       | gate leakage current                  | V <sub>GS</sub> = 20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C   | -     | 2    | 100   | nA   |
|                        |                                       | V <sub>GS</sub> = -20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C  | -     | 2    | 100   | nA   |
| R <sub>DSon</sub>      | drain-source on-state                 | V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 25 °C   | -     | 2.56 | 3.3   | mΩ   |
|                        | resistance                            | $V_{GS} = 7 \text{ V}; I_D = 25 \text{ A}; T_j = 25 ^{\circ}\text{C}$   | -     | 3.6  | 4.5   | mΩ   |
|                        |                                       | V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 100 °C  | -     | 4.1  | 5.3   | mΩ   |
|                        |                                       | V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 175 °C  | -     | 5.8  | 7.5   | mΩ   |
| $R_G$                  | gate resistance                       | f = 1 MHz; T <sub>j</sub> = 25 °C   | [tbd] | 0.74 | [tbd] | Ω    |
| Dynamic ch             | naracteristics                        |   |       |      |       |      |
| Q <sub>G(tot)</sub>    | total gate charge                     | I <sub>D</sub> = 25 A; V <sub>DS</sub> = 50 V; V <sub>GS</sub> = 10 V   | [tbd] | 101  | [tbd] | nC   |
|                        |                                       | I <sub>D</sub> = 0 A; V <sub>DS</sub> = 0 V; V <sub>GS</sub> = 10 V   | -     | 55   | -     | nC   |
| Q <sub>GS</sub>        | gate-source charge                    | I <sub>D</sub> = 25 A; V <sub>DS</sub> = 50 V; V <sub>GS</sub> = 10 V   | [tbd] | 30   | [tbd] | nC   |
| Q <sub>GS(th)</sub>    | pre-threshold gate-<br>source charge  |   | -     | 20   | -     | nC   |
| Q <sub>GS(th-pl)</sub> | post-threshold gate-<br>source charge |   | -     | 10   | -     | nC   |
| $Q_{GD}$               | gate-drain charge                     |   | [tbd] | 20   | [tbd] | nC   |
| V <sub>GS(pl)</sub>    | gate-source plateau<br>voltage        | I <sub>D</sub> = 25 A; V <sub>DS</sub> = 50 V   | -     | 4.5  | -     | V    |
| C <sub>iss</sub>       | input capacitance                     | V <sub>DS</sub> = 50 V; V <sub>GS</sub> = 0 V; f = 1 MHz;   | [tbd] | 7224 | [tbd] | pF   |
| C <sub>oss</sub>       | output capacitance                    | T <sub>j</sub> = 25 °C  | [tbd] | 1700 | [tbd] | pF   |
| C <sub>rss</sub>       | reverse transfer capacitance          |   | [tbd] | 29   | [tbd] | pF   |
| t <sub>d(on)</sub>     | turn-on delay time                    | $V_{DS} = 50 \text{ V}; R_L = 2 \Omega; V_{GS} = 10 \text{ V};$   | -     | 27   | -     | ns   |
| t <sub>r</sub>         | rise time                             | $R_{G(ext)} = 5 \Omega$   | -     | 23   | -     | ns   |
| t <sub>d(off)</sub>    | turn-off delay time                   |   | -     | 59   | -     | ns   |
| t <sub>f</sub>         | fall time                             |   | -     | 32   | -     | ns   |
| Source-drai            | in diode                              |   |       |      |       |      |
| V <sub>SD</sub>        | source-drain voltage                  | $I_S = 25 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$   | -     | 8.0  | 1.2   | V    |
| t <sub>rr</sub>        | reverse recovery time                 | $I_S = 25 \text{ A}$ ; $V_{GS} = 0 \text{ V}$ ; $V_{DS} = 50 \text{ V}$ ; $V_{DS} = 50$ | -     | 56   | -     | ns   |
| 41                     |                                       |   |       |      |       |      |



## 10. Package outline

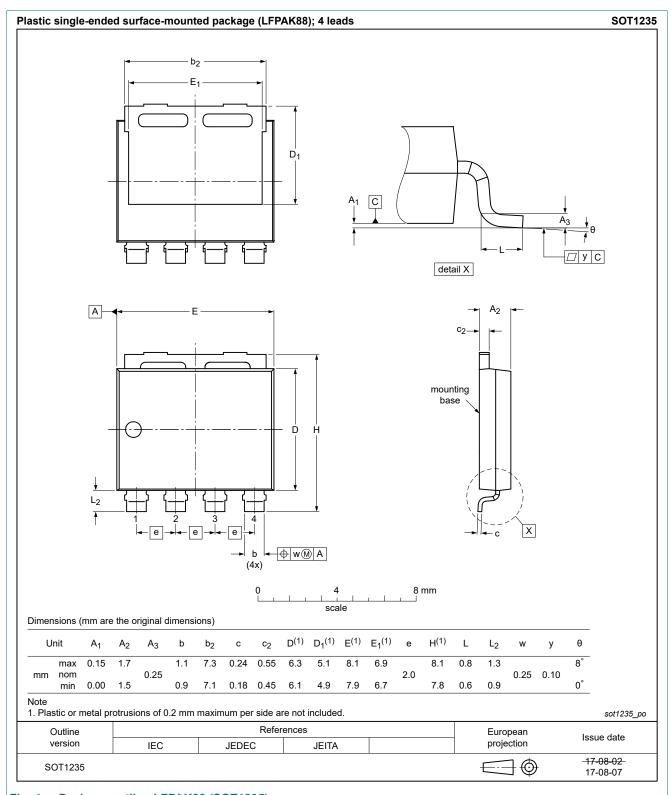
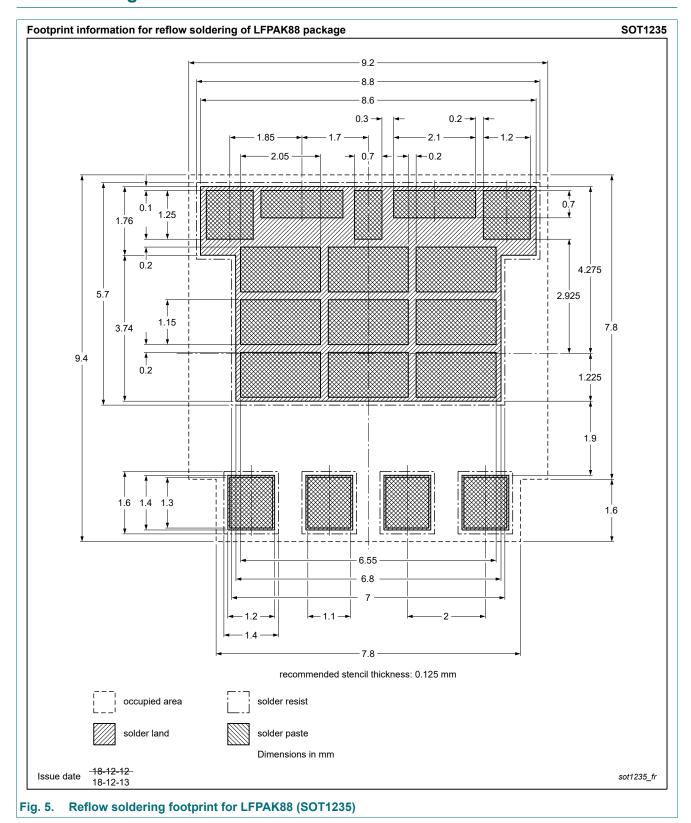


Fig. 4. Package outline LFPAK88 (SOT1235)

## 11. Soldering



### 12. Legal information

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